

## Precision CMOS Analog Switches

### DESCRIPTION

The DG417, DG418, DG419 monolithic CMOS analog switches were designed to provide high performance switching of analog signals. Combining low power, low leakages, high speed, low on-resistance and small physical size, the DG417 series is ideally suited for portable and battery powered industrial and military applications requiring high performance and efficient use of board space.

To achieve high-voltage ratings and superior switching performance, the DG417 series is built on Vishay Siliconix's high voltage silicon gate (HVSG) process. Break-before-make is guaranteed for the DG419, which is an SPDT configuration. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG417 and DG418 respond to opposite control logic levels as shown in the Truth Table.

### FEATURES

- $\pm 15$  V analog signal range
- On-resistance -  $R_{DS(on)}$ : 20  $\Omega$
- Fast switching action -  $t_{ON}$ : 100 ns
- Ultra low power requirements -  $P_D$ : 35 nW
- TTL and CMOS compatible
- MiniDIP and SOIC packaging
- 44 V supply max. rating
- 44 V supply max. rating
- Compliant to RoHS directive 2002/95/EC



Available  
**RoHS\***  
COMPLIANT

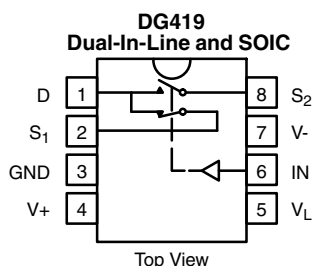
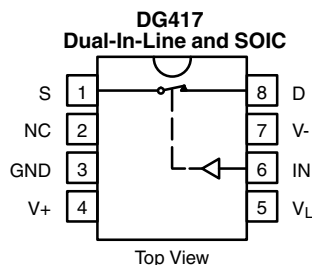
### BENEFITS

- Wide dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- Improved reliability

### APPLICATIONS

- Precision test equipment
- Precision instrumentation
- Battery powered systems
- Sample-and-hold circuits
- Military radios
- Guidance and control systems
- Hard disk drives

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



#### TRUTH TABLE

| Logic | DG417 | DG418 |
|-------|-------|-------|
| 0     | ON    | OFF   |
| 1     | OFF   | ON    |

Logic "0"  $\leq 0.8$  V

Logic "1"  $\geq 2.4$  V

#### TRUTH TABLE DG419

| Logic | SW <sub>1</sub> | SW <sub>2</sub> |
|-------|-----------------|-----------------|
| 0     | ON              | OFF             |
| 1     | OFF             | ON              |

Logic "0"  $\leq 0.8$  V

Logic "1"  $\geq 2.4$  V

\* Pb containing terminations are not RoHS compliant, exemptions may apply

| ORDERING INFORMATION |                       |  |
|----------------------|-----------------------|--|
| Temp. Range          | Package               | Part Number  |
| DG417, DG418         |                       |  |
| - 40 °C to 85 °C     | 8-Pin Plastic MiniDIP | DG417DJ<br>DG417DJ-E3                                |
|                      |                       | DG418DJ<br>DG418DJ-E3                                |
|                      | 8-Pin Narrow SOIC     | DG417DY<br>DG417DY-E3<br>DG417DY-T1<br>DG417DY-T1-E3 |
|                      |                       | DG418DY<br>DG418DY-E3<br>DG418DY-T1<br>DG418DY-T1-E3 |
| DG419                |                       |  |
| - 40 °C to 85 °C     | 8-Pin Plastic MiniDIP | DG419DJ<br>DG419DJ-E3                                |
|                      | 8-Pin Narrow SOIC     | DG419DY<br>DG419DY-E3<br>DG419DY-T1<br>DG419DY-T1-E3 |

| ABSOLUTE MAXIMUM RATINGS                                      |                                    |  |      |
|---|------------------------------------|--|------|
| Parameter (Voltages referenced to V-)                         |                                    | Limit  | Unit |
| V+  |                                    | 44   | V    |
| GND   |                                    | 25   |      |
| V <sub>L</sub>  |                                    | (GND - 0.3) to (V+) + 0.3                                |      |
| Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub> |                                    | (V-) - 2 to (V+) + 2<br>or 30 mA, whichever occurs first |      |
| Current , (Any Terminal) Continuous                           |                                    | 30   | mA   |
| Current, S or D (Pulsed at 1 ms, 10 % Duty Cycle)             |                                    | 100  |      |
| Storage Temperature   | (AK Suffix)                        | - 65 to 150  | °C   |
|   | (DJ, DY Suffix)                    | - 65 to 125  |      |
| Power Dissipation (Package) <sup>b</sup>                      | 8-Pin Plastic MiniDIP <sup>c</sup> | 400  | mW   |
|   | 8-Pin Narrow SOIC <sup>d</sup>     | 400  |      |
|   | 8-Pin CerDIP <sup>e</sup>          | 600  |      |

Notes:

- Signals on S<sub>X</sub>, D<sub>X</sub>, or IN<sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC board.
- Derate 6 mW/°C above 75 °C.
- Derate 6.5 mW/°C above 75 °C.
- Derate 12 mW/°C above 75 °C.

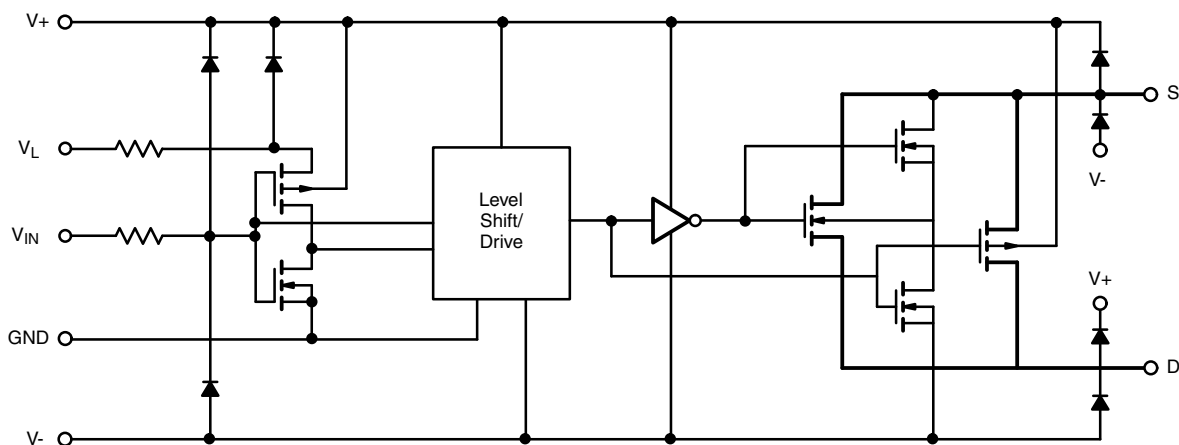
**SCHEMATIC DIAGRAM** Typical Channel


Figure 1.

| SPECIFICATIONS <sup>a</sup>          |                     |  |                    |                    |                   |                               |                   |                              |                   |      |
|--------------------------------------|---------------------|--|--------------------|--------------------|-------------------|-------------------------------|-------------------|------------------------------|-------------------|------|
| Parameter                            | Symbol              | Test Conditions<br>Unless Otherwise Specified<br>V <sub>+</sub> = 15 V, V <sub>-</sub> = - 15 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup> |                    | Temp. <sup>b</sup> | Typ. <sup>c</sup> | A Suffix<br>- 55 °C to 125 °C |                   | D Suffix<br>- 40 °C to 85 °C |                   | Unit |
|                                      |                     |  |                    |                    |                   | Min. <sup>d</sup>             | Max. <sup>d</sup> | Min. <sup>d</sup>            | Max. <sup>d</sup> |      |
| Analog Switch                        |                     |  |                    |                    |                   |                               |                   |                              |                   |      |
| Analog Signal Range <sup>e</sup>     | V <sub>ANALOG</sub> |  |                    | Full               |                   | - 15                          | 15                | - 15                         | 15                | V    |
| Drain-Source On-Resistance           | R <sub>DS(on)</sub> | I <sub>S</sub> = - 10 mA, V <sub>D</sub> = ± 12.5 V<br>V <sub>+</sub> = 13.5 V, V <sub>-</sub> = - 13.5 V  |                    | Room Full          | 20                |                               | 35<br>45          |                              | 35<br>45          | Ω    |
| Switch Off Leakage Current           | I <sub>S(off)</sub> | V <sub>+</sub> = 16.5, V <sub>-</sub> = - 16.5 V<br>V <sub>D</sub> = ± 15.5 V<br>V <sub>S</sub> = ± 15.5 V   | Room Full          | - 0.1              | - 0.25<br>- 20    | 0.25<br>20                    | - 0.25<br>- 5     | 0.25<br>5                    | nA                |      |
|                                      | I <sub>D(off)</sub> |  | DG417<br>Room Full | - 0.1              | - 0.25<br>- 20    | 0.25<br>20                    | - 0.25<br>- 5     | 0.25<br>5                    |                   |      |
|                                      |                     |  | DG419<br>Room Full | - 0.1              | - 0.75<br>- 60    | 0.75<br>60                    | - 0.75<br>- 12    | 0.75<br>12                   |                   |      |
| Channel Off Leakage Current          | I <sub>D(on)</sub>  | V <sub>+</sub> = 16.5 V, V <sub>-</sub> = - 16.5 V<br>V <sub>S</sub> = V <sub>D</sub> = ± 15.5 V   | DG417<br>Room Full | - 0.4              | - 0.4<br>- 40     | 0.4<br>40                     | - 0.4<br>- 10     | 0.4<br>10                    |                   |      |
|                                      |                     |  | DG419<br>Room Full | - 0.4              | - 0.75<br>- 60    | 0.75<br>60                    | - 0.75<br>- 12    | 0.75<br>12                   |                   |      |
| Digital Control                      |                     |  |                    |                    |                   |                               |                   |                              |                   |      |
| Input Current V <sub>IN</sub> Low    | I <sub>IL</sub>     |  |                    | Full               | 0.005             | - 0.5                         | 0.5               | - 0.5                        | 0.5               | μA   |
| Input Current V <sub>IN</sub> High   | I <sub>IH</sub>     |  |                    | Full               | 0.005             | - 0.5                         | 0.5               | - 0.5                        | 0.5               |      |
| Dynamic Characteristics              |                     |  |                    |                    |                   |                               |                   |                              |                   |      |
| Turn-On Time                         | t <sub>ON</sub>     | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = ± 10 V  | DG417<br>DG418     | Room Full          | 100               |                               | 175<br>250        |                              | 175<br>250        | ns   |
| Turn-Off Time                        | t <sub>OFF</sub>    | See Switching Time Test Circuit  | DG417<br>DG418     | Room Full          | 60                |                               | 145<br>210        |                              | 145<br>210        |      |
| Transition Time                      | t <sub>TRANS</sub>  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S1</sub> = ± 10 V, V <sub>S2</sub> = ± 10 V   | DG419              | Room Full          |                   |                               | 175<br>250        |                              | 175<br>250        |      |
| Break-Before-Make Time Delay (DG403) | t <sub>D</sub>      | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S1</sub> = V <sub>S2</sub> = ± 10 V   | DG419              | Room               | 13                | 5                             |                   | 5                            |                   |      |
| Charge Injection                     | Q                   | C <sub>L</sub> = 10 nF, V <sub>gen</sub> = 0 V, R <sub>gen</sub> = 0 Ω   |                    | Room               | 60                |                               |                   |                              |                   | pC   |

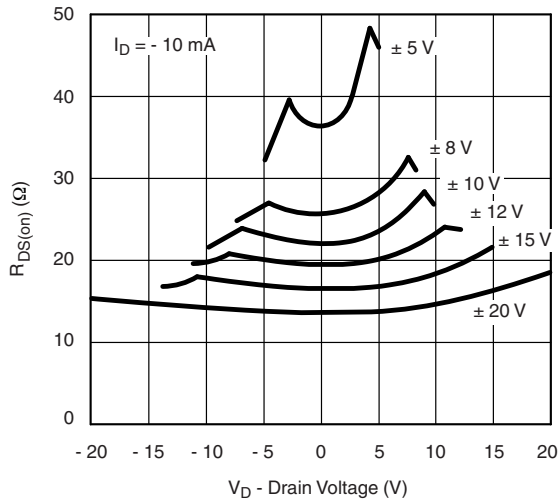
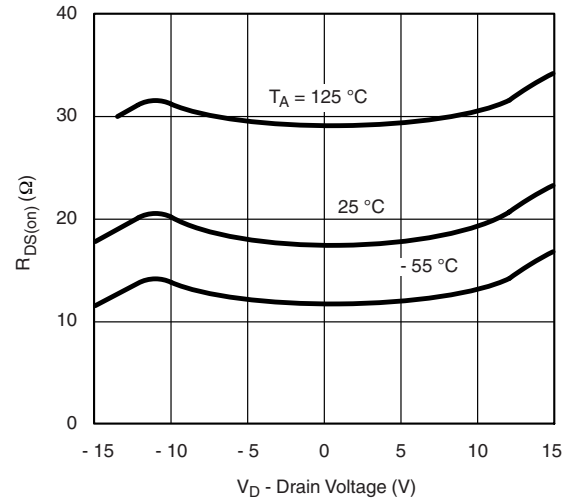
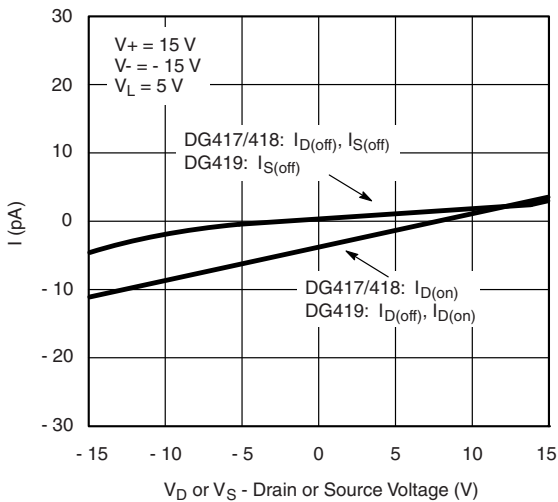
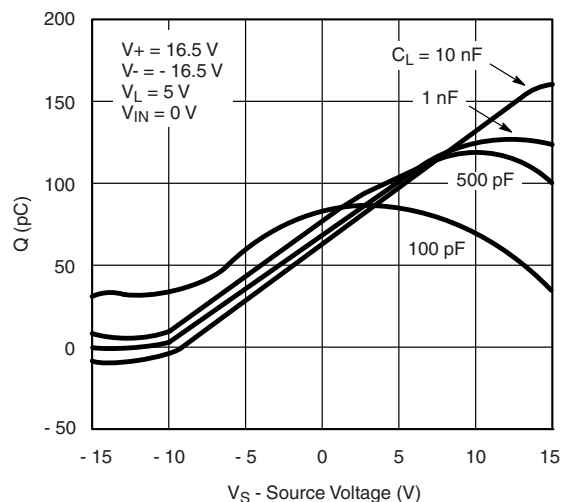
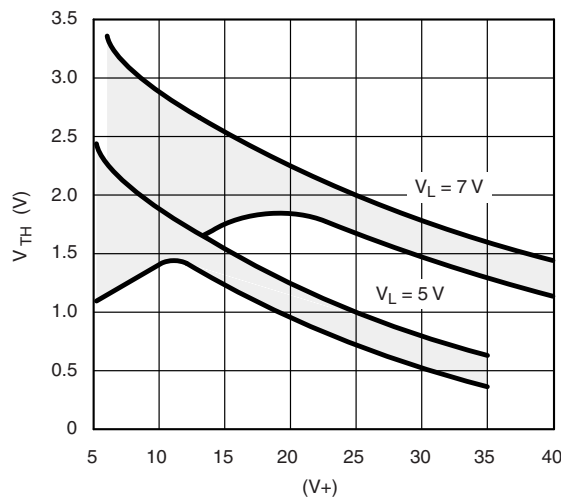
| SPECIFICATIONS <sup>a</sup> |                     |  |  |                    |                   |                               |                   |                              |                   |      |
|-----------------------------|---------------------|--|--|--------------------|-------------------|-------------------------------|-------------------|------------------------------|-------------------|------|
| Parameter                   | Symbol              | Test Conditions<br>Unless Otherwise Specified<br>V <sub>+</sub> = 15 V, V <sub>-</sub> = - 15 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup> |  | Temp. <sup>b</sup> | Typ. <sup>c</sup> | A Suffix<br>- 55 °C to 125 °C |                   | D Suffix<br>- 40 °C to 85 °C |                   | Unit |
|                             |                     |  |  |                    |                   | Min. <sup>d</sup>             | Max. <sup>d</sup> | Min. <sup>d</sup>            | Max. <sup>d</sup> |      |
| Dynamic Characteristics     |                     |  |  |                    |                   |                               |                   |                              |                   |      |
| Source Off Capacitance      | C <sub>S(off)</sub> | f = 1 MHz, V <sub>S</sub> = 0 V  |  | Room               | 8                 |                               |                   |                              |                   | pF   |
| Drain Off Capacitance       | C <sub>D(off)</sub> |  |  | DG417<br>DG418     | Room              | 8                             |                   |                              |                   |      |
| Channel On Capacitance      | C <sub>D(on)</sub>  | f = 1 MHz, V <sub>S</sub> = 0 V  |  | DG417<br>DG418     | Room              | 30                            |                   |                              |                   |      |
|                             |                     |  |  | DG419              | Room              | 35                            |                   |                              |                   |      |
| Power Supplies              |                     |  |  |                    |                   |                               |                   |                              |                   |      |
| Positive Supply Current     | I <sub>+</sub>      | V <sub>+</sub> = 16.5 V, V <sub>-</sub> = - 16.5 V<br>V <sub>IN</sub> = 0 or 5 V   |  | Room<br>Full       | 0.001             |                               | 1<br>5            |                              | 1<br>5            | μA   |
| Negative Supply Current     | I <sub>-</sub>      |  |  | Room<br>Full       | - 0.001           | - 1<br>- 5                    |                   | - 1<br>- 5                   |                   |      |
| Logic Supply Current        | I <sub>L</sub>      |  |  | Room<br>Full       | 0.001             |                               | 1<br>5            |                              | 1<br>5            |      |
| Ground Current              | I <sub>GND</sub>    |  |  | Room<br>Full       | - 0.0001          | - 1<br>- 5                    |                   | - 1<br>- 5                   |                   |      |

| SPECIFICATIONS <sup>a</sup> for Unipolar Supplies |                     |   |                    |                   |                               |                   |                              |                   |      |
|---|---------------------|---|--------------------|-------------------|-------------------------------|-------------------|------------------------------|-------------------|------|
| Parameter   | Symbol              | Test Conditions<br>Unless Otherwise Specified<br>V <sub>+</sub> = 12 V, V <sub>-</sub> = 0 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup> | Temp. <sup>b</sup> | Typ. <sup>c</sup> | A Suffix<br>- 55 °C to 125 °C |                   | D Suffix<br>- 40 °C to 85 °C |                   | Unit |
|   |                     |   |                    |                   | Min. <sup>d</sup>             | Max. <sup>d</sup> | Min. <sup>d</sup>            | Max. <sup>d</sup> |      |
| Analog Switch                                     |                     |   |                    |                   |                               |                   |                              |                   |      |
| Analog Signal Range <sup>e</sup>                  | V <sub>ANALOG</sub> |   | Full               |                   | 0                             | 12                | 0                            | 12                | V    |
| Drain-Source On-Resistance                        | R <sub>DS(on)</sub> | I <sub>S</sub> = - 10 mA, V <sub>D</sub> = 3.8 V<br>V <sub>+</sub> = 10.8 V   | Room               | 40                |                               |                   |                              |                   | Ω    |
| Dynamic Characteristics                           |                     |   |                    |                   |                               |                   |                              |                   |      |
| Turn-On Time                                      | t <sub>ON</sub>     | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF, V <sub>S</sub> = 8 V<br>See Switching Time Test Circuit   | Room               | 110               |                               |                   |                              |                   | ns   |
| Turn-Off Time                                     | t <sub>OFF</sub>    |   | Room               | 40                |                               |                   |                              |                   |      |
| Break-Before-Make Time Delay                      | t <sub>D</sub>      | DG419 Only<br>R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF  | Room               | 60                |                               |                   |                              |                   |      |
| Charge Injection                                  | Q                   | C <sub>L</sub> = 10 nF, V <sub>gen</sub> = 0 V, R <sub>gen</sub> = 0 Ω  | Room               | 5                 |                               |                   |                              |                   | pC   |
| Power Supplies                                    |                     |   |                    |                   |                               |                   |                              |                   |      |
| Positive Supply Current                           | I <sub>+</sub>      | V <sub>+</sub> = 13.2 V, V <sub>L</sub> = 5.25 V<br>V <sub>IN</sub> = 0 or 5 V  | Room               | 0.001             |                               |                   |                              |                   | μA   |
| Negative Supply Current                           | I <sub>-</sub>      |   | Room               | - 0.001           |                               |                   |                              |                   |      |
| Logic Supply Current                              | I <sub>L</sub>      |   | Room               | 0.001             |                               |                   |                              |                   |      |
| Ground Current                                    | I <sub>GND</sub>    |   | Room               | - 0.001           |                               |                   |                              |                   |      |

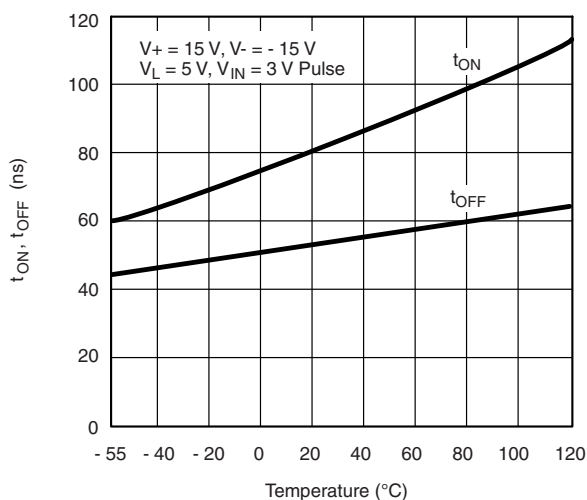
Notes:

- Refer to Process Option Flowchart.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.

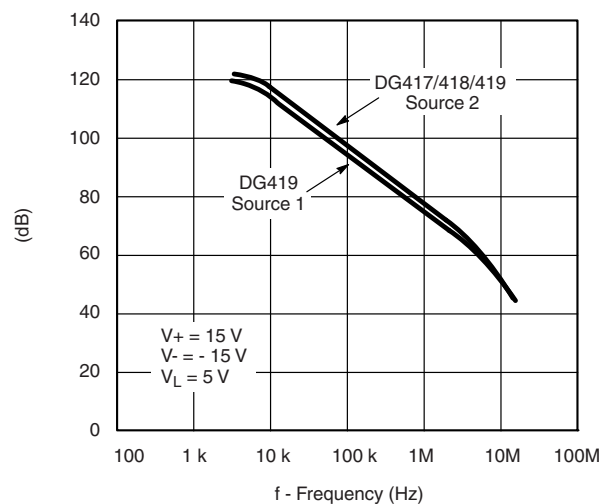
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

 **$R_{DS(on)}$  vs.  $V_D$  and Supply Voltage**

 **$R_{DS(on)}$  vs. Temperature**

**Leakage Currents vs. Analog Voltage**

**Drain Charge Injection**

**Input Switching Threshold vs. Supply Voltages**

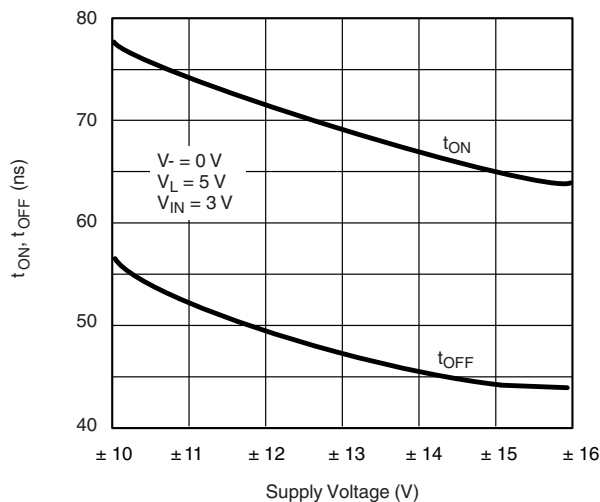
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



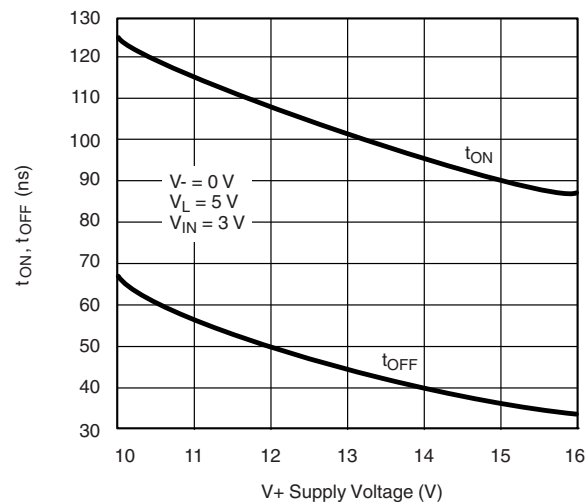
Switching Time vs. Temperature



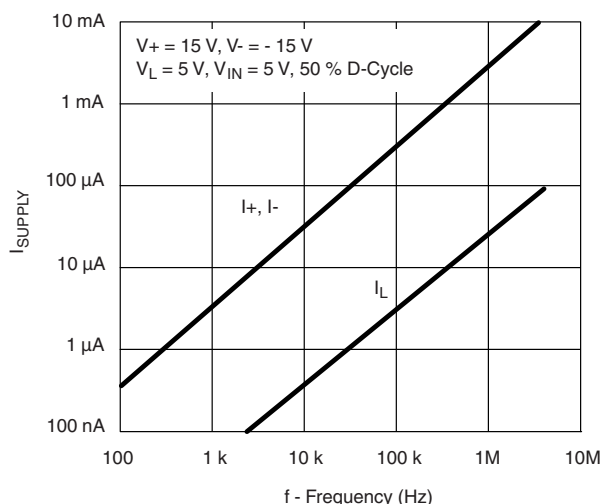
Crosstalk and Off Isolation vs. Frequency



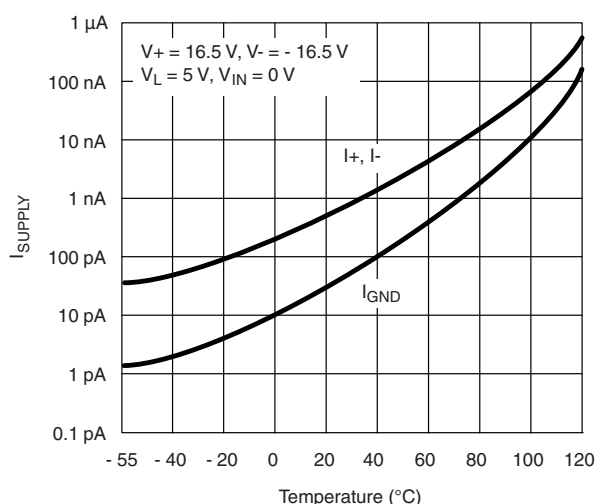
Switching Time vs. Supply Voltages



Switching Time vs.  $V_+$



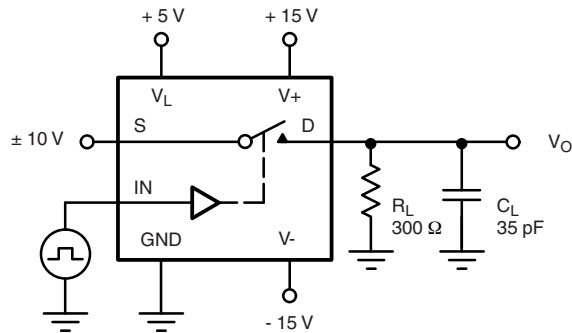
Power Supply Currents vs. Switching Frequency



Supply Current vs. Temperature

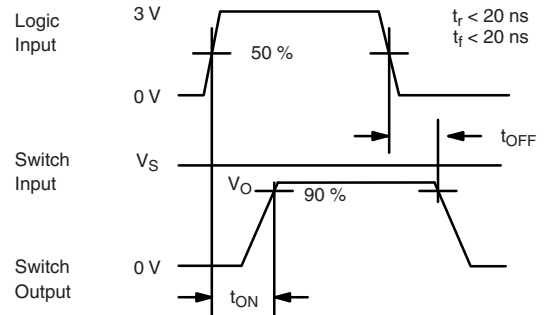
## TEST CIRCUITS

$V_O$  is the steady state output with the switch on.



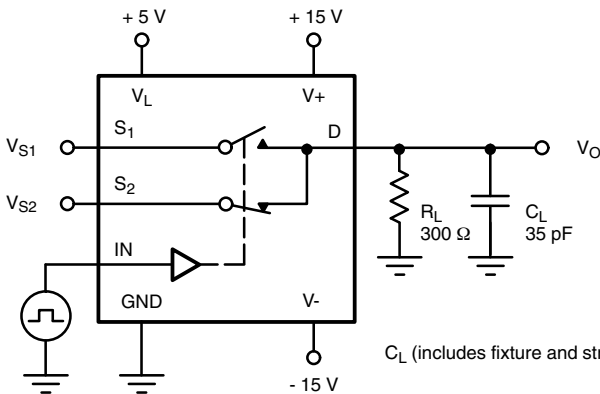
$C_L$  (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 2. Switching Time (DG417, DG418)



$C_L$  (includes fixture and stray capacitance)

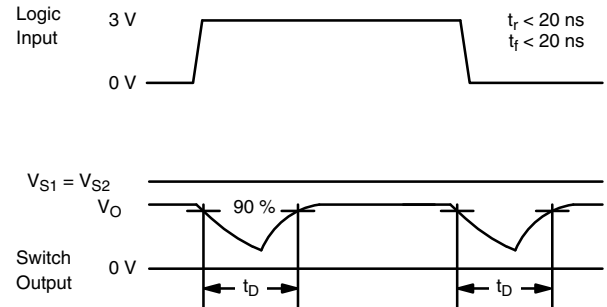
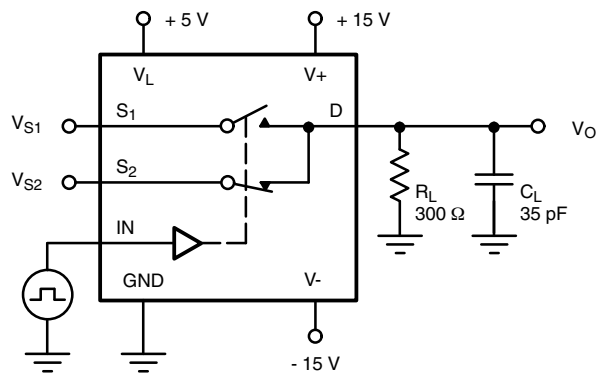


Figure 3. Break-Before-Make (DG419)



$C_L$  (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$

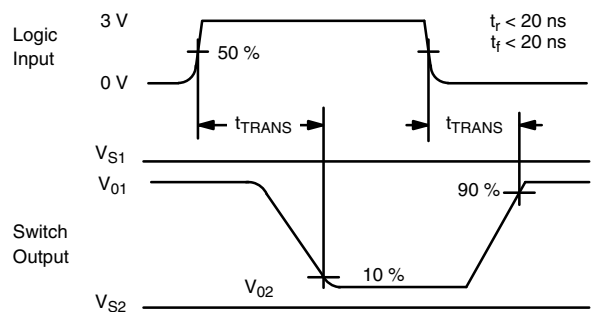


Figure 4. Transition Time (DG419)

## TEST CIRCUITS

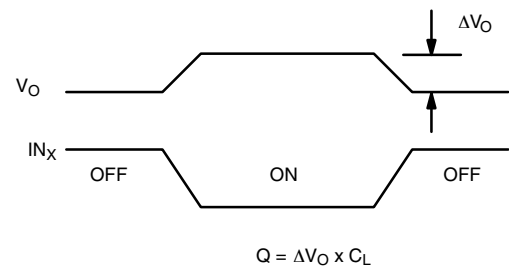
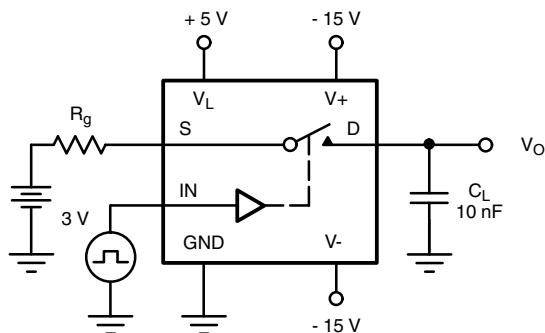


Figure 5. Charge Injection

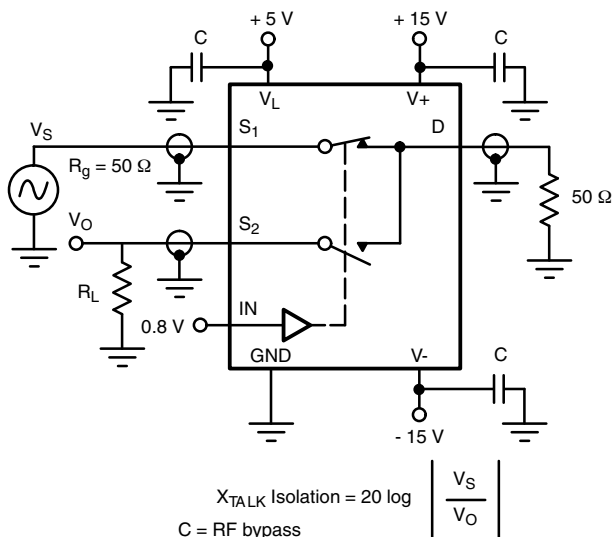


Figure 6. Crosstalk (DG419)

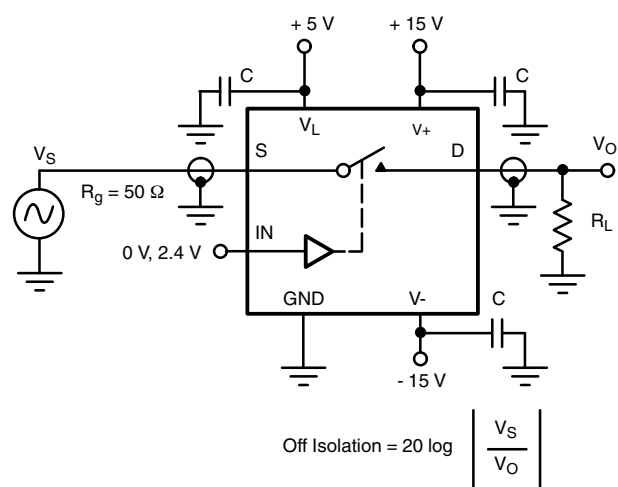


Figure 7. Off Isolation

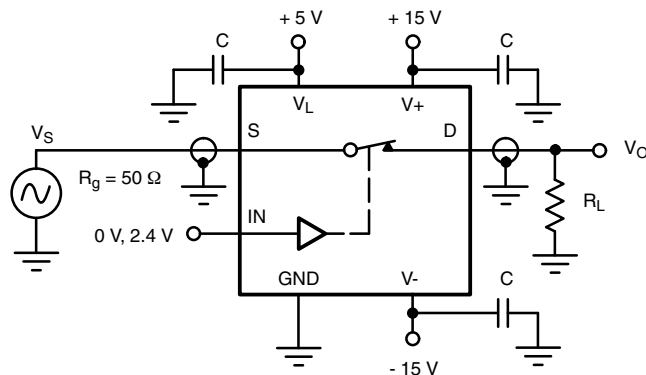


Figure 8. Insertion Loss



## TEST CIRCUITS

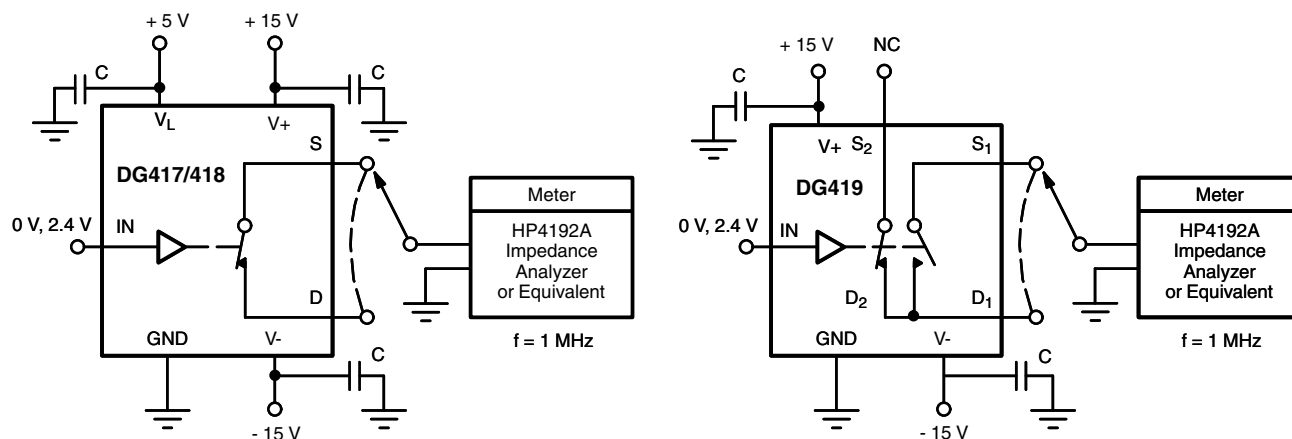


Figure 9. Source/Drain Capacitances

## APPLICATIONS

### Switched Signal Powers Analog Switch

The analog switch in Figure 10 derives power from its input signal, provided the input signal amplitude exceeds 4 V and its frequency exceeds 1 kHz.

This circuit is useful when signals have to be routed to either of two remote loads. Only three conductors are required: one for the signal to be switched, one for the control signal and a common return.

A positive input pulse turns on the clamping diode  $D_1$  and charges  $C_1$ . The charge stored on  $C_1$  is used to power the chip; operation is satisfactory because the switch requires less than 1  $\mu\text{A}$  of stand-by supply current. Loading of the signal source is imperceptible. The DG419's on-resistance is a low 100  $\Omega$  for a 5 V input signal.

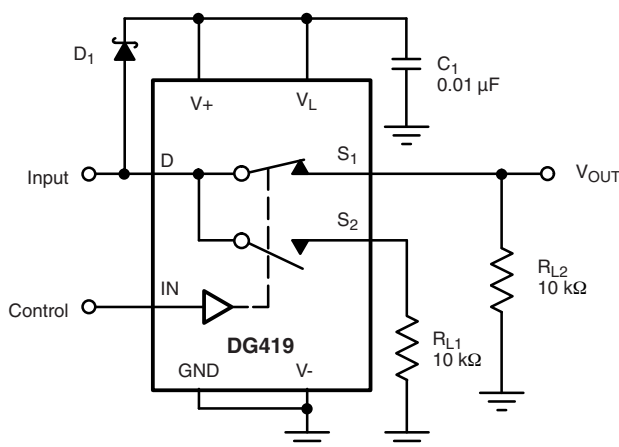


Figure 10. Switched Signal Powers Remote SPDT Analog Switch

## APPLICATIONS

### Micropower UPS Transfer Switch

When  $V_{CC}$  drops to 3.3 V, the DG417 changes states, closing  $SW_1$  and connecting the backup cell, as shown in Figure 10.  $D_1$  prevents current from leaking back towards the rest of the circuit. Current consumption by the CMOS analog switch is around 100 pA; this ensures that most of the power available is applied to the memory, where it is really needed. In the stand-by mode, hundreds of A are sufficient to retain memory data.

When the 5 V supply comes back up, the resistor divider senses the presence of at least 3.5 V, and causes a new change of state in the analog switch, restoring normal operation.

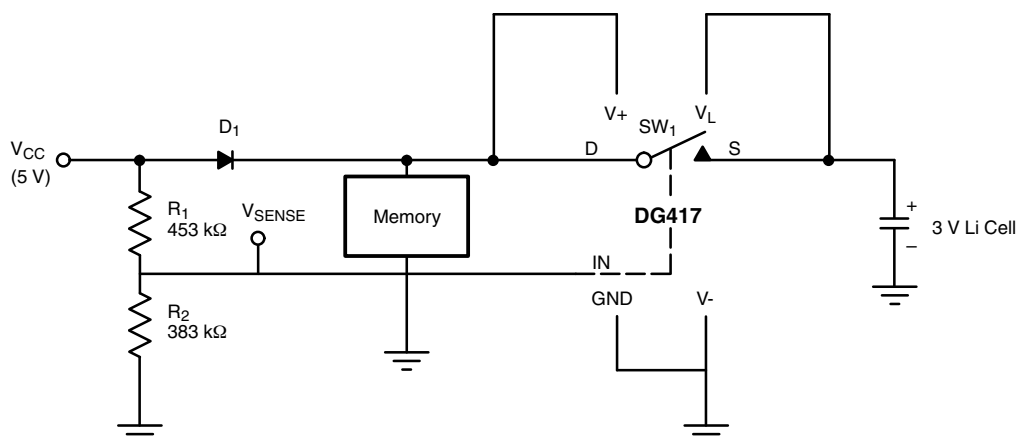


Figure 11. Micropower UPS Circuit

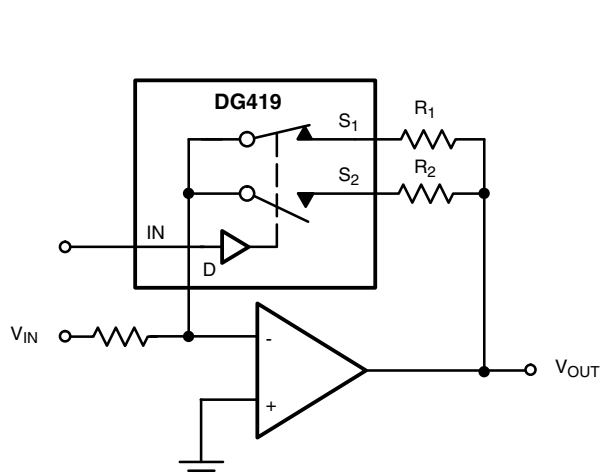


Figure 12. Programmable Gain Amplifier

### Programmable Gain Amplifier

The DG419, as shown in figure 11, allows accurate gain selection in a small package. Switching into virtual ground reduces distortion caused by  $R_{DS(on)}$  variation as a function of analog signal amplitude.

### GaAs FET Driver

The DG419, as shown in figure 12 may be used as a GaAs FET driver. It translates a TTL control signal into - 8 V, 0 V level outputs to drive the gate.

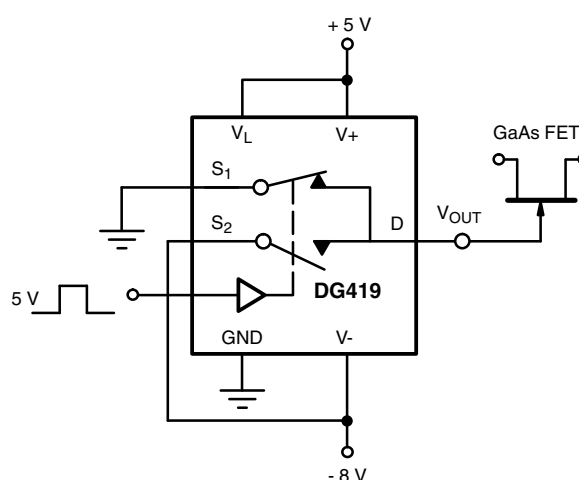
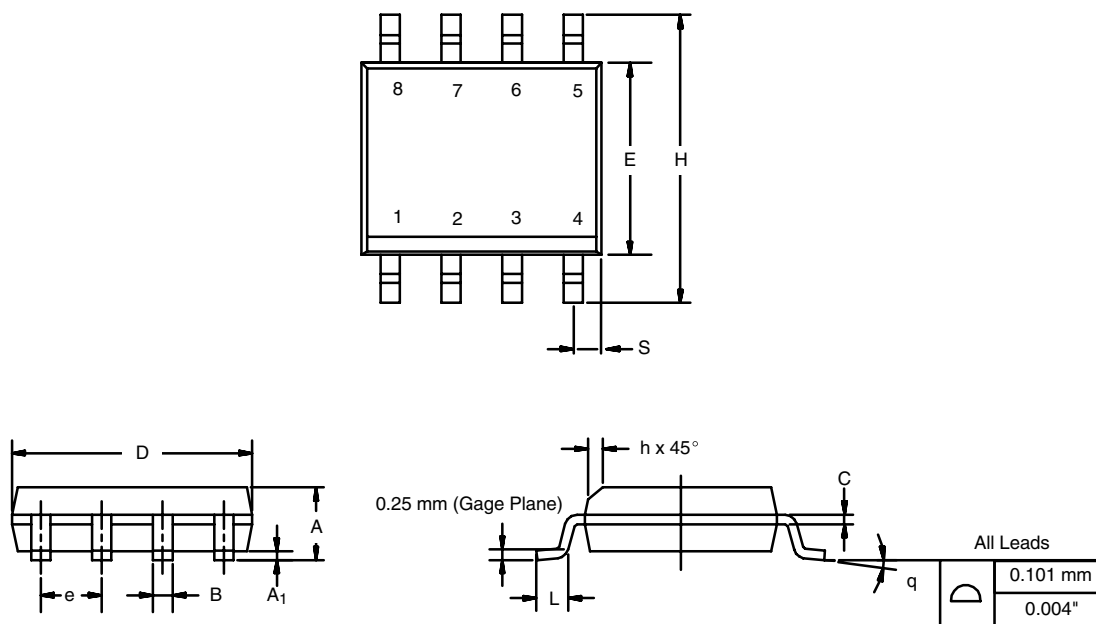


Figure 13. GaAs FET Driver

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?70051](http://www.vishay.com/ppg?70051).

## SOIC (NARROW): 8-LEAD

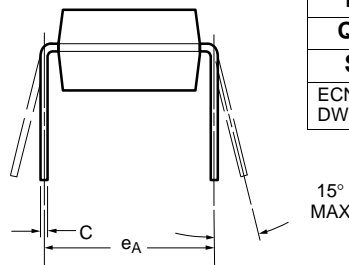
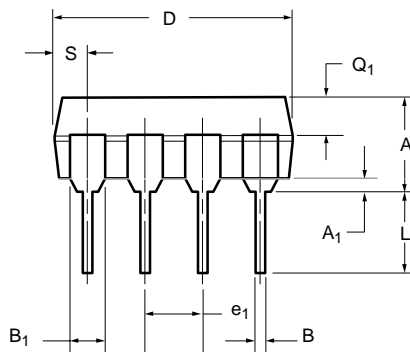
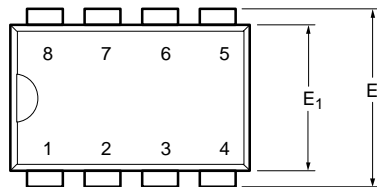
JEDEC Part Number: MS-012



| DIM                            | MILLIMETERS |      | INCHES    |       |
|--------------------------------|-------------|------|-----------|-------|
|                                | Min         | Max  | Min       | Max   |
| A                              | 1.35        | 1.75 | 0.053     | 0.069 |
| A <sub>1</sub>                 | 0.10        | 0.20 | 0.004     | 0.008 |
| B                              | 0.35        | 0.51 | 0.014     | 0.020 |
| C                              | 0.19        | 0.25 | 0.0075    | 0.010 |
| D                              | 4.80        | 5.00 | 0.189     | 0.196 |
| E                              | 3.80        | 4.00 | 0.150     | 0.157 |
| e                              | 1.27 BSC    |      | 0.050 BSC |       |
| H                              | 5.80        | 6.20 | 0.228     | 0.244 |
| h                              | 0.25        | 0.50 | 0.010     | 0.020 |
| L                              | 0.50        | 0.93 | 0.020     | 0.037 |
| q                              | 0°          | 8°   | 0°        | 8°    |
| S                              | 0.44        | 0.64 | 0.018     | 0.026 |
| ECN: C-06527-Rev. I, 11-Sep-06 |             |      |           |       |
| DWG: 5498                      |             |      |           |       |



### PDIP: 8-LEAD



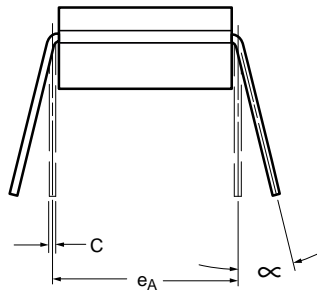
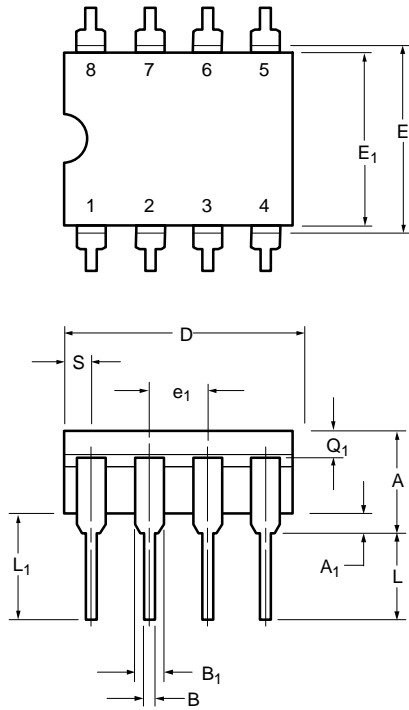
| Dim                  | MILLIMETERS |       | INCHES |       |
|----------------------|-------------|-------|--------|-------|
|                      | Min         | Max   | Min    | Max   |
| <b>A</b>             | 3.81        | 5.08  | 0.150  | 0.200 |
| <b>A<sub>1</sub></b> | 0.38        | 1.27  | 0.015  | 0.050 |
| <b>B</b>             | 0.38        | 0.51  | 0.015  | 0.020 |
| <b>B<sub>1</sub></b> | 0.89        | 1.65  | 0.035  | 0.065 |
| <b>C</b>             | 0.20        | 0.30  | 0.008  | 0.012 |
| <b>D</b>             | 9.02        | 10.92 | 0.355  | 0.430 |
| <b>E</b>             | 7.62        | 8.26  | 0.300  | 0.325 |
| <b>E<sub>1</sub></b> | 5.59        | 7.11  | 0.220  | 0.280 |
| <b>e<sub>1</sub></b> | 2.29        | 2.79  | 0.090  | 0.110 |
| <b>e<sub>A</sub></b> | 7.37        | 7.87  | 0.290  | 0.310 |
| <b>L</b>             | 2.79        | 3.81  | 0.110  | 0.150 |
| <b>Q<sub>1</sub></b> | 1.27        | 2.03  | 0.050  | 0.080 |
| <b>S</b>             | 0.76        | 1.65  | 0.030  | 0.065 |

ECN: S-03946—Rev. E, 09-Jul-01  
DWG: 5478

NOTE: End leads may be half leads.



### CERDIP: 8-LEAD



| Dim            | MILLIMETERS |       | INCHES    |       |
|----------------|-------------|-------|-----------|-------|
|                | Min         | Max   | Min       | Max   |
| A              | 4.06        | 5.08  | 0.160     | 0.200 |
| A <sub>1</sub> | 0.51        | 1.14  | 0.020     | 0.045 |
| B              | 0.38        | 0.51  | 0.015     | 0.020 |
| B <sub>1</sub> | 1.14        | 1.65  | 0.045     | 0.065 |
| C              | 0.20        | 0.30  | 0.008     | 0.012 |
| D              | 9.40        | 10.16 | 0.370     | 0.400 |
| E              | 7.62        | 8.26  | 0.300     | 0.325 |
| E <sub>1</sub> | 6.60        | 7.62  | 0.260     | 0.300 |
| e <sub>1</sub> | 2.54 BSC    |       | 0.100 BSC |       |
| e <sub>A</sub> | 7.62 BSC    |       | 0.300 BSC |       |
| L              | 3.18        | 3.81  | 0.125     | 0.150 |
| L <sub>1</sub> | 3.18        | 5.08  | 0.150     | 0.200 |
| Q <sub>1</sub> | 1.27        | 2.16  | 0.050     | 0.085 |
| S              | 0.64        | 1.52  | 0.025     | 0.060 |
| α              | 0°          | 15°   | 0°        | 15°   |

ECN: S-03946—Rev. C, 09-Jul-01  
DWG: 5348



## Mounting LITTLE FOOT®, SO-8 Power MOSFETs

Wharton McDaniel

Surface-mounted LITTLE FOOT power MOSFETs use integrated circuit and small-signal packages which have been modified to provide the heat transfer capabilities required by power devices. Leadframe materials and design, molding compounds, and die attach materials have been changed, while the footprint of the packages remains the same.

See Application Note 826, *Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs*, (<http://www.vishay.com/ppg?72286>), for the basis of the pad design for a LITTLE FOOT SO-8 power MOSFET. In converting this recommended minimum pad to the pad set for a power MOSFET, designers must make two connections: an electrical connection and a thermal connection, to draw heat away from the package.

In the case of the SO-8 package, the thermal connections are very simple. Pins 5, 6, 7, and 8 are the drain of the MOSFET for a single MOSFET package and are connected together. In a dual package, pins 5 and 6 are one drain, and pins 7 and 8 are the other drain. For a small-signal device or integrated circuit, typical connections would be made with traces that are 0.020 inches wide. Since the drain pins serve the additional function of providing the thermal connection to the package, this level of connection is inadequate. The total cross section of the copper may be adequate to carry the current required for the application, but it presents a large thermal impedance. Also, heat spreads in a circular fashion from the heat source. In this case the drain pins are the heat sources when looking at heat spread on the PC board.

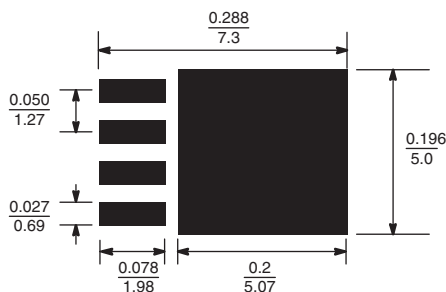


Figure 1. Single MOSFET SO-8 Pad Pattern With Copper Spreading

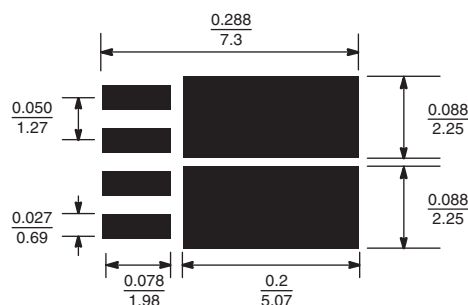


Figure 2. Dual MOSFET SO-8 Pad Pattern With Copper Spreading

The minimum recommended pad patterns for the single-MOSFET SO-8 with copper spreading (Figure 1) and dual-MOSFET SO-8 with copper spreading (Figure 2) show the starting point for utilizing the board area available for the heat-spreading copper. To create this pattern, a plane of copper overlies the drain pins. The copper plane connects the drain pins electrically, but more importantly provides planar copper to draw heat from the drain leads and start the process of spreading the heat so it can be dissipated into the ambient air. These patterns use all the available area underneath the body for this purpose.

Since surface-mounted packages are small, and reflow soldering is the most common way in which these are affixed to the PC board, “thermal” connections from the planar copper to the pads have not been used. Even if additional planar copper area is used, there should be no problems in the soldering process. The actual solder connections are defined by the solder mask openings. By combining the basic footprint with the copper plane on the drain pins, the solder mask generation occurs automatically.

A final item to keep in mind is the width of the power traces. The absolute minimum power trace width must be determined by the amount of current it has to carry. For thermal reasons, this minimum width should be at least 0.020 inches. The use of wide traces connected to the drain plane provides a low impedance path for heat to move away from the device.

## RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads  
Dimensions in Inches/(mm)

[Return to Index](#)



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